

30V N+P Dual Channel Enhancement Mode Power MOSFET

Description

WMB38DH03TS uses advanced power trench technology that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.



Features

N-Channel

$$V_{DS} = 30V, I_{D} = 38A$$

$$R_{DS(on)} < 10.5 m\Omega$$
 @ $V_{GS} = 10V$

$$R_{DS(on)}$$
 < 15m Ω @ V_{GS} = 4.5 V

P-Channel

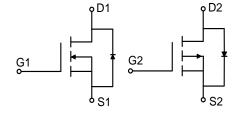
$$V_{DS} = -30V, I_{D} = -28A$$

$$R_{DS(on)}$$
 < 22m Ω @ V_{GS} = -10 V

$$R_{DS(on)}$$
 < 30m Ω @ V_{GS} = -4.5 V

- Green Device Available
- 100% EAS Guaranteed
- RoHS Compliant & Halogen-Free
- Optimized for High Speed Smooth Switching

RoHS



Applications

- Power Management Switches
- DC/DC Converter

Absolute Maximum Ratings (T_A= 25°C, unless otherwise noted)

Parameter		Symbol	Value		Unit
Drain-Source Voltage		V _{DS}	30	-30	V
Gate-Source Voltage		V _{GS}	±20	±20	V
Continuous Drain Current	T _C =25°C	ΙD	38	-28	A
Continuous Drain Current	Tc=100°C		23.7	-17.5	
Pulsed Drain Current ¹		I _{DM}	152	-112	А
Single Pulse Avalanche Energy ²		EAS	33.8	39.2	mJ
Total Power Dissipation Tc=25°C		P _D	27.2		W
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55 to 150		°C

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction-to-Ambient ³	Reja	70	°C/W
Thermal Resistance from Junction-to-Case	Rejc	4.6	°C/W



Electrical Characteristics N-Channel (T_J = 25°C, unless otherwise noted)

Parameter		Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static Characteristics				1			
Drain-Source Breakdown Vo	oltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 250μA	30	-	-	V
Gate-Body Leakage Curren		Igss	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	±100	nA
Zero Gate Voltage Drain	T _J =25°C	1	V _{DS} = 30V, V _{GS} = 0V	-	-	1	μА
Current	T _J =100°C	- I _{DSS}		-	-	100	
Gate-Threshold Voltage		V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	1	1.5	2	V
5 . 6 . 5	4	R _{DS(on)}	V _{GS} = 10V, I _D = 20A	-	8.2	10.5	
Drain-Source on-Resistance	Drain-Source on-Resistance ⁴		V _{GS} = 4.5V, I _D = 10A	-	11	15	mΩ
Forward Transconductance	ļ	g fs	V _{DS} = 10V, I _D = 20A	-	62	-	S
Dynamic Characteristic	s ⁵	•	1		I.		
Input Capacitance		Ciss		-	1060	-	
Output Capacitance Reverse Transfer Capacitance		Coss	V _{DS} = 15V, V _{GS} =0V, f =1MHz	-	125	-	pF
		Crss		-	110	-	
Gate Resistance		R _G	f =1MHz	-	3.4	-	Ω
Switching Characteristi	CS ⁵				l .		
Total Gate Charge	Total Gate Charge		V _{GS} = 10V, V _{DS} = 15V, I _D = 20A	-	20.7	-	nC
Gate-Source Charge		Q _{gs}		-	3.9	-	
Gate-Drain Charge		Q_{gd}		-	3.8	-	1
Turn-on Delay Time		t _{d(on)}		-	5.5	-	
Rise Time		t _r	$V_{GS} = 10V, V_{DD} = 15V,$ $R_{G} = 3\Omega, I_{D} = 20A$	-	4.9	-	ns
Turn-off Delay Time		t _{d(off)}		-	21.8	-	
Fall Time		t _f		-	7.3	-	
Body Diode Reverse Recovery Time		trr		-	16	-	ns
Body Diode Reverse Recovery Charge		Qrr	- I _F = 20A, di/dt = 100A/μs	-	3.2	-	nC
Drain-Source Body Diode Characteristics							
Diode Forward Voltage ⁴		V _{SD}	I _S = 20A, V _{GS} = 0V	-	-	1.2	V
Continuous Source Current	T _C =25°C	Is	-	-	-	38	Α

Notes:

- 1. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C.
- 2. The test condition is V_{DD} =25V, V_{GS} =10V, L=0.4mH, I_{AS} =13A.
- 3. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
- 4. The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2%.
- 5. This value is guaranteed by design hence it is not included in the production test.



Electrical Characteristics P-Channel (T_J = 25°C, unless otherwise noted)

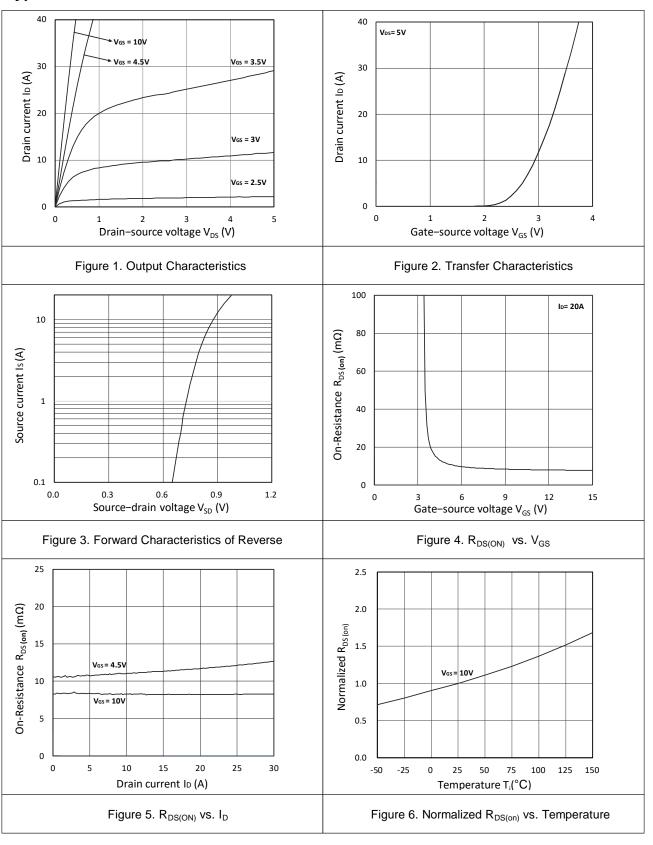
Parameter		Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static Characteristics							
Drain-Source Breakdown Volta	age	V _{(BR)DSS}	V _{GS} = 0V, I _D = -250µA	-30	-	-	V
Gate-body Leakage current		I _{GSS}	V _{DS} = 0V, V _{GS} = ±20V	-	-	±100	nA
Zero Gate Voltage Drain	T _J =25°C	_	V _{DS} = -30V, V _{GS} = 0V	-	-	-1	μА
Current	T _J =100°C	I _{DSS}		-	-	-100	
Gate-Threshold Voltage		V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	-1	-1.5	-2	V
Dunin Course On Braintage 4			V _{GS} = -10V, I _D = -20A	-	17	22	mΩ
Drain-Source On-Resistance ⁴		R _{DS(on)}	V _{GS} = -4.5V, I _D = -10A	-	24	30	
Forward Transconductance ⁴		g fs	V _{DS} = -10V, I _D = -20A	-	25	-	S
Dynamic Characteristics5							
Input Capacitance		Ciss		-	970	-	pF
Output Capacitance		Coss	$V_{DS} = -15V, V_{GS} = 0V,$ f =1MHz	-	131	-	
Reverse Transfer Capacitance)	C _{rss}		-	107	-	
Gate Resistance		R _g	f =1MHz	-	10	-	Ω
Switching Characteristics	5						
Total Gate Charge		Qg	V _{GS} = -10V, V _{DS} = -15V, I _D = -20A	-	20.2	-	nC
Gate-Source Charge		Q _{gs}		-	3.8	-	
Gate-Drain Charge		\mathbf{Q}_{gd}		-	3	-	1
Turn-On Delay Time		t _{d(on)}		-	7.5	-	
Rise Time		t _r	V _{GS} = -10V, V _{DD} = -15V,	-	16	-	200
Turn-Off Delay Time		t _{d(off)}	$R_G = 3\Omega$, $I_D = -20A$	-	49	-	ns
Fall Time		t _f		-	32	-	
Body Diode Reverse Recovery Time		trr		-	21	-	ns
Body Diode Reverse Recovery Charge		Qrr	IF = -20A, di/dt = -100A/μs	-	12.5	-	nC
Drain-Source Body Diode	Character	istics	'	•	ı	ı	
Diode Forward Voltage ⁴		V _{SD}	Is = -20A, V _{GS} = 0V	-	-	-1.2	V
Continuous Source Current	T _C =25°C	Is	-	-	-	-28	Α

Note:

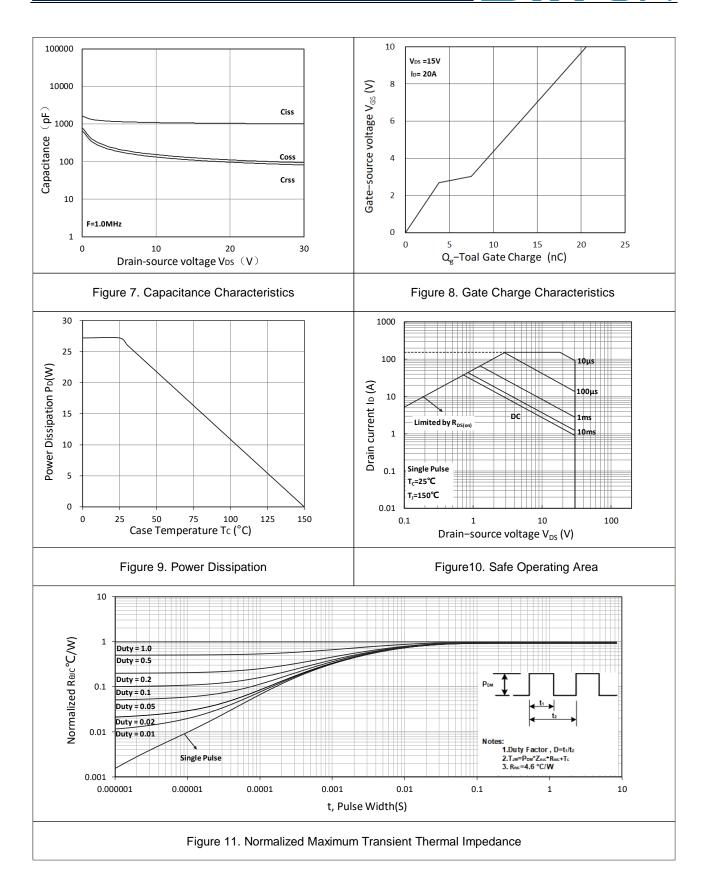
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- 2. The test condition is V_{DD} = -25V, V_{GS} = -10V, L= 0.4mH, I_{AS} = -14A.
- 3. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
- 4. The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2%.
- 5. This value is guaranteed by design hence it is not included in the production test.



Typical Characteristics: N-Channel

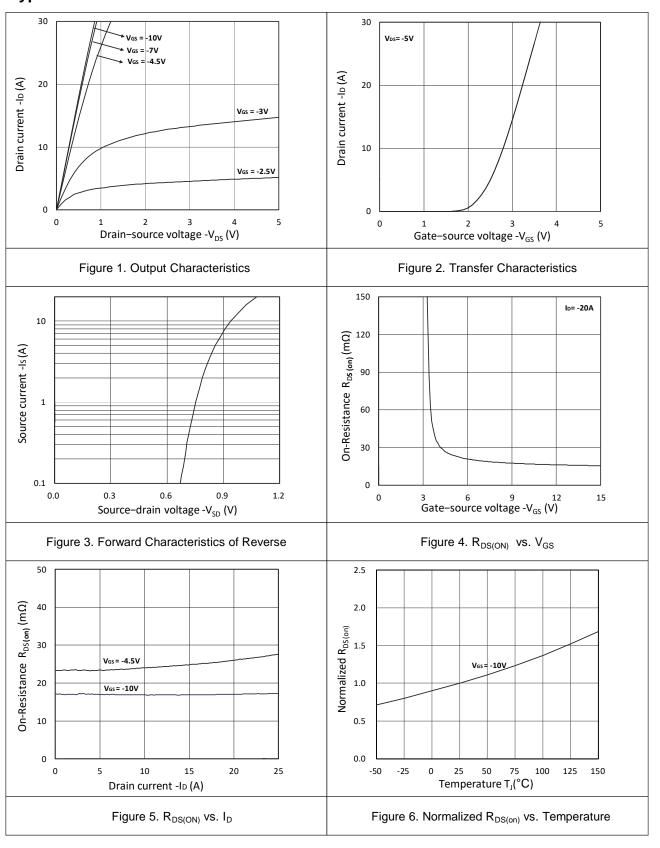




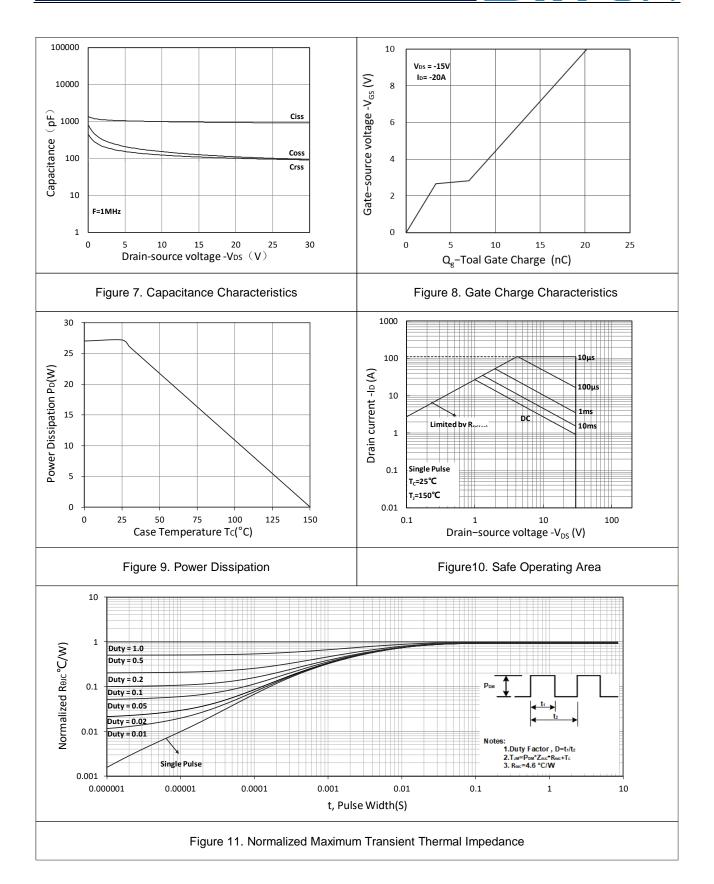




Typical Characteristics P-Channel









Test Circuit

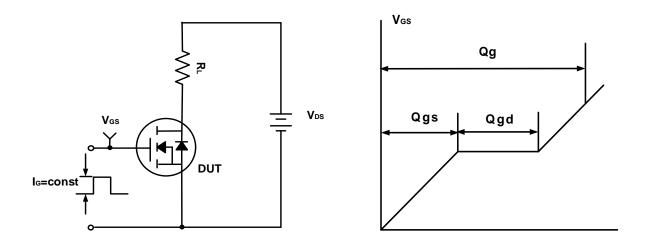


Figure A. Gate Charge Test Circuit & Waveforms

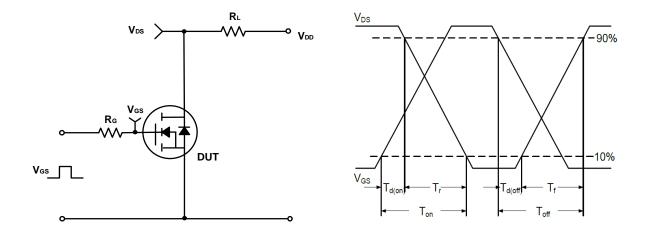


Figure B. Switching Test Circuit & Waveforms

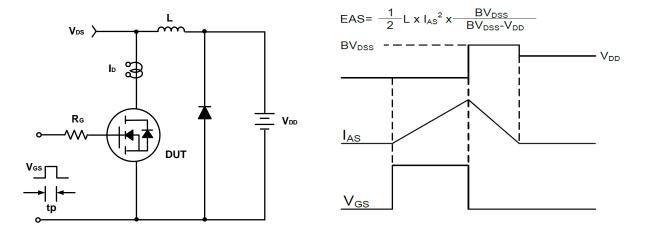
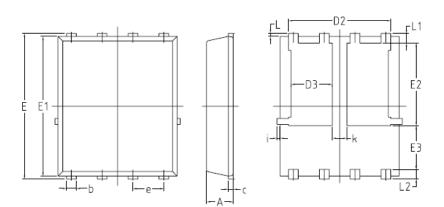


Figure C. Unclamped Inductive Switching Circuit & Waveforms



Mechanical Dimensions for Dual PDFN5060-8L





COMMON DIMENSIONS

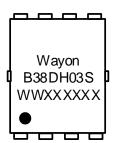
OVADOL	MM			
SYMBOL	MIN	MAX		
А	0.90	1.17		
b	0.33	0.51		
С	0.20	BSC		
D	4.80	5.40		
D1	4.80	5.00		
D2	3.95	4.45		
D3	1.55	1.80		
Е	5.90	6.15		
E1	5.65	5.85		
E2	3.30	3.78		
E3	1.10	/		
е	1.27BSC			
L	0.05	0.25		
L1	0.38	0.61		
L2	0.38	0.71		
i	/	0.18		
k	0.50	0.70		



Ordering Information

Part	Package	Marking	Packing method	
WMB38DH03TS	PDFN5060-8L	B38DH03S	Tape and Reel	

Marking Information



B38DH03S = Device code

WWXXXXXX Date code

Contact Information

No.1001, Shiwan(7) Road, Pudong District, Shanghai, P.R.China.201207 Tel: 86-21-50310888 Fax: 86-21-50757680 Email: market@way-on.com

WAYON website: http://www.way-on.com

For additional information, please contact your local Sales Representative.

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Product Specification Statement

- 1. The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.
- 2. The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. WAYON shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and WAYON assumes no responsibility for the application of the product.
- 3. WAYON strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, WAYON cannot guarantee that the information provided in the product specification is entirely accurate and error-free. WAYON shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications. WAYON reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with WAYON to ensure that the product specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult WAYON in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.
- 4. Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.
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